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March 2015

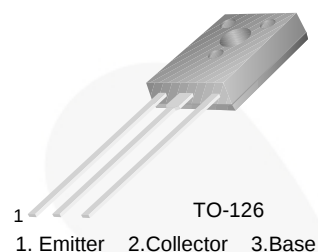
BD136 / BD138 / BD140 PNP Epitaxial Silicon Transistor

Features

- Complement to BD135, BD137 and BD139 respectively

Applications

- Medium Power Linear and Switching



Ordering Information

Part Number	Marking	Package	Packing Method
BD13610S	BD136-10	TO-126 3L	Bulk
BD13610STU	BD136-10	TO-126 3L	Rail
BD13616S	BD136-16	TO-126 3L	Bulk
BD13616STU	BD136-16	TO-126 3L	Rail
BD13810STU	BD138-10	TO-126 3L	Rail
BD13816STU	BD138-16	TO-126 3L	Rail
BD14010STU	BD140-10	TO-126 3L	Rail
BD14016S	BD140-16	TO-126 3L	Bulk
BD14016STU	BD140-16	TO-126 3L	Rail

BD136 / BD138 / BD140 — PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		Value	Unit
V_{CBO}	Collector-Base Voltage	BD136	-45	V
		BD138	-60	
		BD140	-80	
V_{CEO}	Collector-Emitter Voltage	BD136	-45	V
		BD138	-60	
		BD140	-80	
V_{EBO}	Emitter-Base Voltage		-5	V
I_C	Collector Current (DC)		-1.5	A
I_C	Collector Current (Pulse)		-3.0	A
I_B	Base Current		-0.5	A
P_C	Collector Dissipation	$T_C = 25^\circ\text{C}$	12.5	W
		$T_A = 25^\circ\text{C}$	1.25	
T_J	Junction Temperature		150	$^\circ\text{C}$
T_{STG}	Storage Temperature		-55 to +150	$^\circ\text{C}$

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		Conditions	Min.	Typ.	Max.	Unit
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage ⁽¹⁾	BD136	$I_C = -30\text{ mA}, I_B = 0$	-45			V
		BD138		-60			
		BD140		-80			
I_{CBO}	Collector Cut-Off Current		$V_{CB} = -30\text{ V}, I_E = 0$			-0.1	μA
I_{EBO}	Emitter Cut-Off Current		$V_{EB} = -5\text{ V}, I_C = 0$			-10	μA
h_{FE1}	DC Current Gain ⁽¹⁾		$V_{CE} = -2\text{ V}, I_C = -5\text{ mA}$	25			
h_{FE2}	DC Current Gain ⁽¹⁾		$V_{CE} = -2\text{ V}, I_C = -0.5\text{ A}$	25			
h_{FE3}	DC Current Gain ⁽¹⁾		$V_{CE} = -2\text{ V}, I_C = -150\text{ mA}$	40		250	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ⁽¹⁾		$I_C = -500\text{ mA}, I_B = -50\text{ mA}$			-0.5	V
$V_{BE(on)}$	Base-Emitter On Voltage ⁽¹⁾		$V_{CE} = -2\text{ V}, I_C = -0.5\text{ A}$			-1	V

Note:

1. Pulse test: pulse width = 350 μs , duty cycle = 2.0% pulsed.

h_{FE} Classification

Classification	10	16
h_{FE3}	63 ~ 160	100 ~ 250

Typical Performance Characteristics

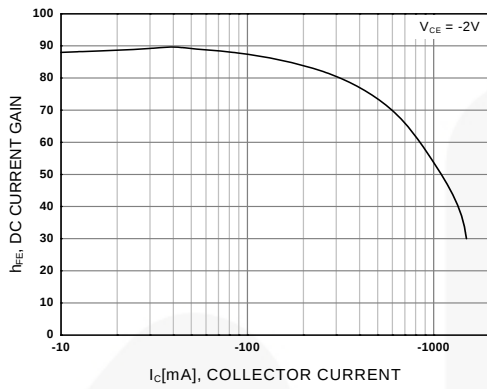


Figure 1. DC Current Gain

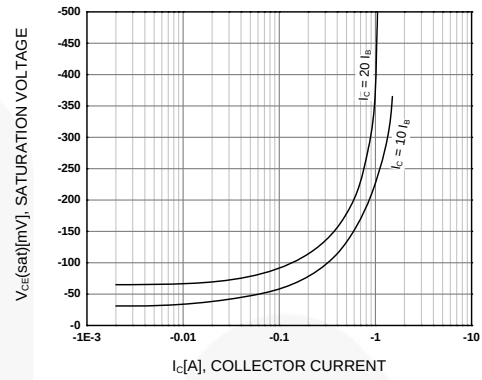


Figure 2. Collector-Emitter Saturation Voltage

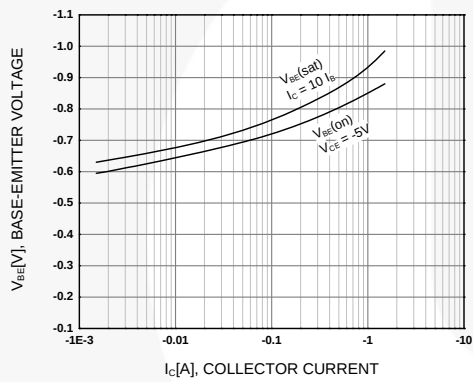


Figure 3. Base-Emitter Voltage

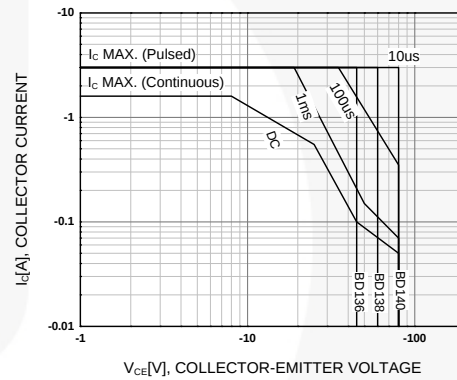


Figure 4. Safe Operating Area

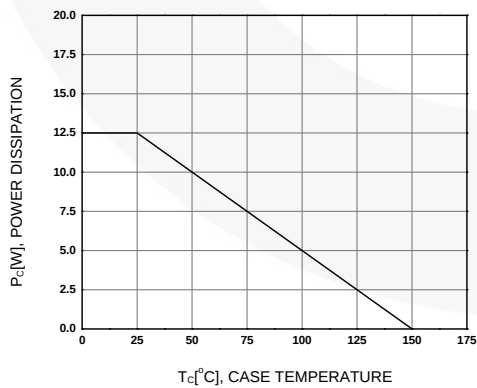


Figure 5. Power Derating

Technical drawing of a 3X 1.50mm pitch connector. The drawing shows a top view and a side view.

Top View Dimensions:

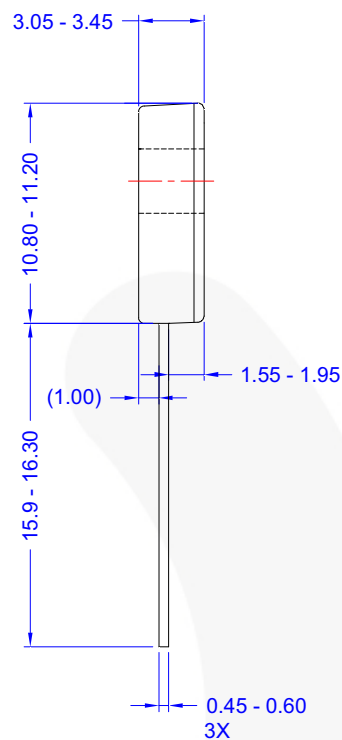
- Overall width: 8.30 (7.70 MAX)
- Overall height: 14.20 MAX
- Central hole diameter: $\phi 3.20$
- Four corner holes (diameter not specified)
- Width of mounting tabs: 3.80 - 4.00

Side View Dimensions:

- Height of mounting tabs: 2.29
- Angle: 3°
- Pitch: 1.50
- Number of positions: 3X

Surface Finish:

- Surface texture symbol: $\sqrt{0.254}$ (M)



PRODUCTION CODE	TERMINAL LENGTH "D"
TSSTU	3.45-4.05
TSTU	2.36-2.96
NONE (STD LENGTH)	12.76-13.36

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E) DRAWING FILE NAME AND REVISION : MKT-TO126AArev1



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